



Features

- Uncooled laser diode with MQW structure
- 5mW CW operation at -40 to $+85^{\circ}\text{C}$
- High temperature operation without active cooling
- Hermetically sealed active component
- Built-in InGaAs monitor photodiode
- Complies with Telcordia(Bellcore) GR-468-CORE
- TO-56 packaging with a flat window cap or a ball lens cap
- RoHS compliance available

Absolute Maximum Rating ($T_c=25^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Optical Output Power	P_o	10(CW)	mW
LD Reverse Voltage	V_{RLD}	2	V
LD Forward Current	I_{FLD}	150	mA
PD Reverse Voltage	V_{RPD}	10	V
PD Forward Current	I_{FPD}	2	mA
Operating Temperature	T_{opr}	-40 to $+85$	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-40 to $+85$	$^{\circ}\text{C}$

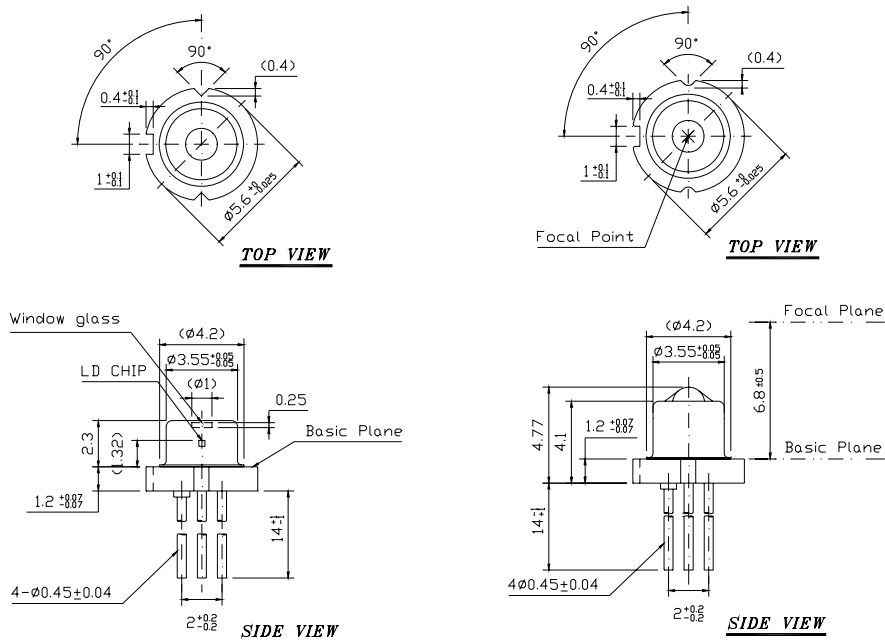
Optical and Electrical Characteristics($T_c=25^{\circ}\text{C}$)

Parameter	Symbol	Min.	Typical	Max.	Unit	Test Condition
Slope Efficiency	SE	0.3	0.35	-	mW/mA	CW, $P_o=5\text{mW}$
Flat window cap		0.2	0.3	-		
Ball lens cap						
Threshold Current	I_{th}	-	10	15	mA	CW, $P_o=5\text{mW}$
Optical output power	P_o	5	-	-	mW	CW, kink free
Peak Wavelength	λ	1290	1310	1330	nm	Note
Spectral Width	$\Delta\lambda$	-	2	5	nm	CW, $P_o=5\text{mW}$
Forward Voltage	V_F	-	1.2	1.5	V	CW, $P_o=5\text{mW}$

Beam Divergence	$\theta_{//}$	-	25	-	deg.	CW, $P_o=5mW$, FWHM
Flat window cap	θ_{\perp}	-	35	-		
Rise/Fall Time	t_r / t_f	-	-	0.5	ns	10-90%
PD Monitor Current	I_m	100	-	-	μA	CW, $P_o=5mW$, $V_{RPD}=2V$
PD Dark Current	I_{DARK}	-	-	0.1	μA	$V_{RPD}=5V$
PD Capacitance	C_t	-	6	15	pF	$V_{RPD}=5V$, $f=1MHz$

Note: Selected wavelength is available for WDM application

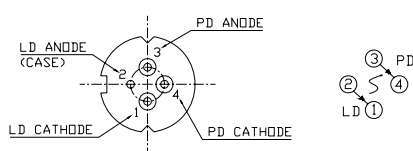
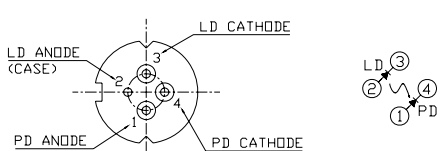
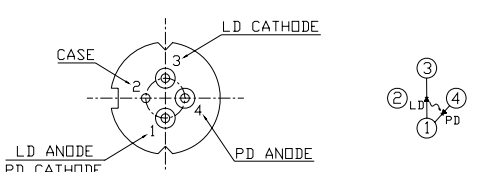
Mechanical Drawing



Flat window Cap

Ball Lens Cap

LD Pin Assignment

Model	PIN Assignment (Bottom View)
A Type	 <p>The diagram shows the bottom view of the A Type laser diode. The LD ANODE (CASE) is at pin 2, LD CATHODE is at pin 1, PD ANODE is at pin 3, and PD CATHODE is at pin 4. The pin assignment is shown as LD 1, LD 2, PD 3, PD 4.</p>
B Type	 <p>The diagram shows the bottom view of the B Type laser diode. The LD ANODE (CASE) is at pin 2, LD CATHODE is at pin 3, PD ANODE is at pin 1, and PD CATHODE is at pin 4. The pin assignment is shown as LD 3, LD 2, PD 1, PD 4.</p>
D Type	 <p>The diagram shows the bottom view of the D Type laser diode. The LD ANODE (CASE) is at pin 2, LD CATHODE is at pin 3, PD ANODE is at pin 4, and PD CATHODE is at pin 1. The pin assignment is shown as LD 3, LD 2, PD 4, PD 1.</p>

Order Information

Available Options:

C-13-001-E-XX
C-13-001-E-XX-G5
C-13-001-E-XX-GR

Note: XX=A,AB,AD,B,BB,BD

C - 13 - 001 - E - X X - XX

Application

Wavelength

Data rate

Header

Cap

Pin out

RoHS compliance

C= Communicaton

13= 1310nm

001 = \leq 1.25G

E= TO-56

A= Flat window
B= Ball Lens

No symbol= A
B= B
D= D

Blank = RoHS non-compliant product
G5 = RoHS 5/6-compliant product (lead exemption)
GR = Full RoHS compliant product (no exemption)

Warnings

Handling Precautions: This device is susceptible to damage as a result of electrostatic discharge (ESD). A static free environment is highly recommended. Follow guidelines according to proper ESD procedures.

Laser Safety: Radiation emitted by laser devices can be dangerous to human eyes. Avoid eye exposure to direct or indirect radiation.

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Contact

U.S.A. Headquarters

20550 Nordhoff Street
Chatsworth, CA 91311
USA
Tel: +1-818-773-9044
Fax: +1-818-773-0261
sales@sourcephotonics.com

China

Building #2&5, West Export Processing Zone
No. 8 Kexin Road, Hi-Tech Zone
Chengdu, 611731, China
Tel: +86-28-8795-8788
Fax: +86-28-8795-8789
sales@sourcephotonics.com.cn

Taiwan

9F, No 81, Shui Lee Rd.
Hsinchu, 300, Taiwan
R.O.C.
Tel: +886-3-5169222
Fax: +886-3-5169213
sales@sourcephotonics.com.tw